

PHOTOCOUPLER PS2711-1

HIGH CTR 4-PIN SOP PHOTOCOUPLER

-NEPOC Series-

DESCRIPTION

The PS2711-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor in a plastic SOP for high density applications.

The package is an SOP (Small Outline Package) type for high density mounting applications.

FEATURES

- High current transfer ratio (CTR = 200% TYP. @ IF = 1mA)
- High isolation voltage (BV = 3 750 Vr.m.s.)
- Small and thin package (4-pin SOP)
- Ordering number of tape product: PS2711-1-F3, F4
- Pb-free product
- · Safety standards
 - UL approved: File No. E72422
 - DIN EN60747-5-2 (VDE0884 Part2) approved (Option)

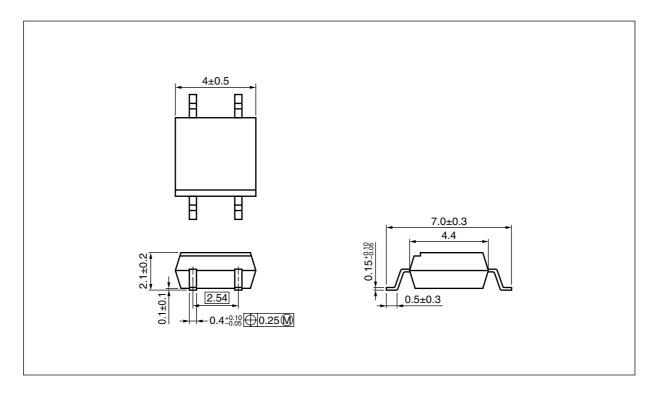
PIN CONNECTION (Top View) 1. Anode 2. Cathode 3. Emitter 4. Collector

APPLICATIONS

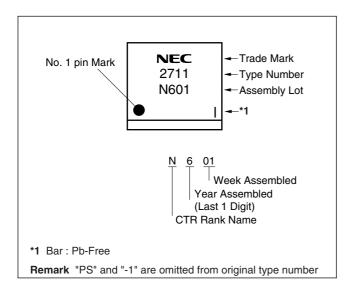
- Programmable logic controllers
- · Small power supply
- · Hybrid IC
- Modem/FAX

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PACKAGE DIMENSIONS (UNIT: mm)



MARKING EXAMPLE





★ ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS2711-1	PS2711-1-A	Pb-Free	Magazine case 100 pcs	Standard products	PS2711-1
PS2711-1-F3	PS2711-1-F3-A		Embossed Tape 3 500 pcs/reel	(UL approved)	
PS2711-1-F4	PS2711-1-F4-A				
PS2711-1-V	PS2711-1-V-A		Magazine case 100 pcs	DIN EN60747-5-2	
PS2711-1-V-F3	PS2711-1-V-F3-A		Embossed Tape 3 500 pcs/reel	(VDE0884 Part2)	
PS2711-1-V-F4	PS2711-1-V-F4-A			Approved (Option)	

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (Unless otherwise specified, T_A = 25°C)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	50	mA
	Reverse Voltage	VR	6	٧
	Power Dissipation Derating	⊿P₀/°C	0.8	mW/°C
	Power Dissipation	Po	80	mW
	Peak Forward Current [™]	IFP	0.5	Α
Transistor	Collector to Emitter Voltage	Vceo	40	V
	Emitter to Collector Voltage	Veco	5	V
	Collector Current	lc	40	mA
	Power Dissipation Derating	⊿Pc/°C	1.5	mW/°C
	Power Dissipation	Pc	150	mW
Isolation Voltage ^{*2}		BV	3 750	Vr.m.s.
Operating Ambient Temperature		TA	-55 to +100	°C
Storage Temperature		T _{stg}	-55 to +150	°C

^{*1} PW = 100 μ s, Duty Cycle = 1%

3

^{*2} AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.



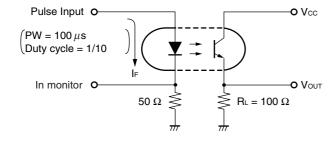
ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	I _F = 5 mA		1.15	1.4	V
	Reverse Current	lR	V _R = 5 V			5	μΑ
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz		30		pF
Transistor	Collector to Emitter Dark Current	Iceo	IF = 0 mA, VcE = 40 V			100	nA
Coupled	Current Transfer Ratio	CTR	IF = 1 mA, VcE = 5 V	100	200	400	%
	Collector Saturation Voltage	VCE (sat)	IF = 1 mA, Ic = 0.2 mA			0.3	V
	Isolation Resistance	R _{I-O}	Vi-o = 1 kVDC	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.4		pF
	Rise Time*2	t r	$Vcc = 5 \text{ V}, \text{ Ic} = 2 \text{ mA}, \text{ RL} = 100 \Omega$		4		μs
	Fall Time ^{*2}	t f			5		

*1 CTR rank

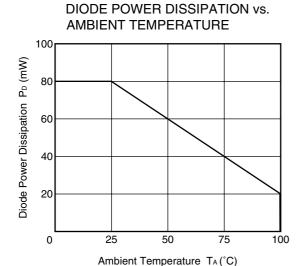
N: 100 to 400 (%) K: 200 to 400 (%) L: 150 to 300 (%) M: 100 to 200 (%)

*2 Test circuit for switching time

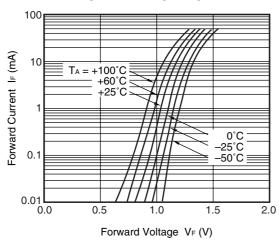


NEC

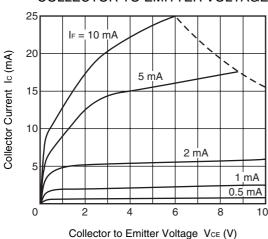
TYPICAL CHARACTERISTICS (Unless otherwise specified, TA = 25°C)



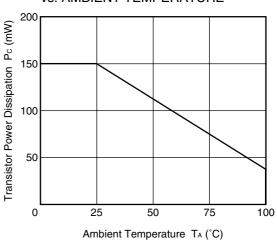
FORWARD CURRENT vs. FORWARD VOLTAGE



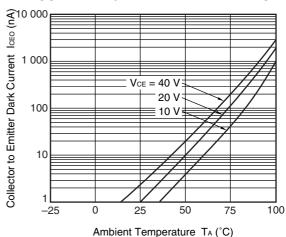
COLLECTOR CURRENT vs.
COLLECTOR TO EMITTER VOLTAGE



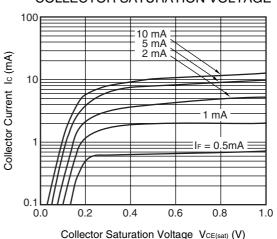
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE

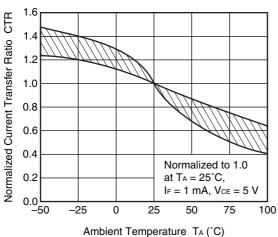


COLLECTOR CURRENT vs.
COLLECTOR SATURATION VOLTAGE

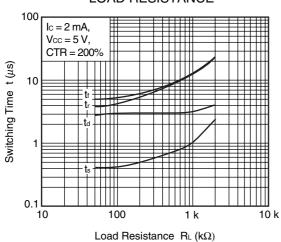


Remark The graphs indicate nominal characteristics.

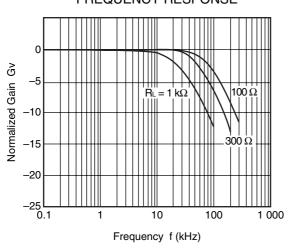
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



SWITCHING TIME vs. LOAD RESISTANCE

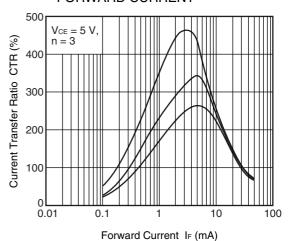


FREQUENCY RESPONSE

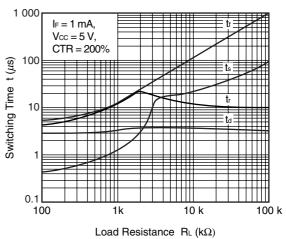


Remark The graphs indicate nominal characteristics.

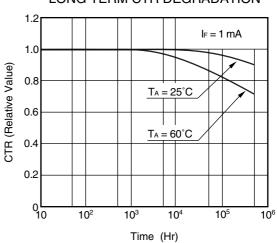
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



SWITCHING TIME vs. LOAD RESISTANCE

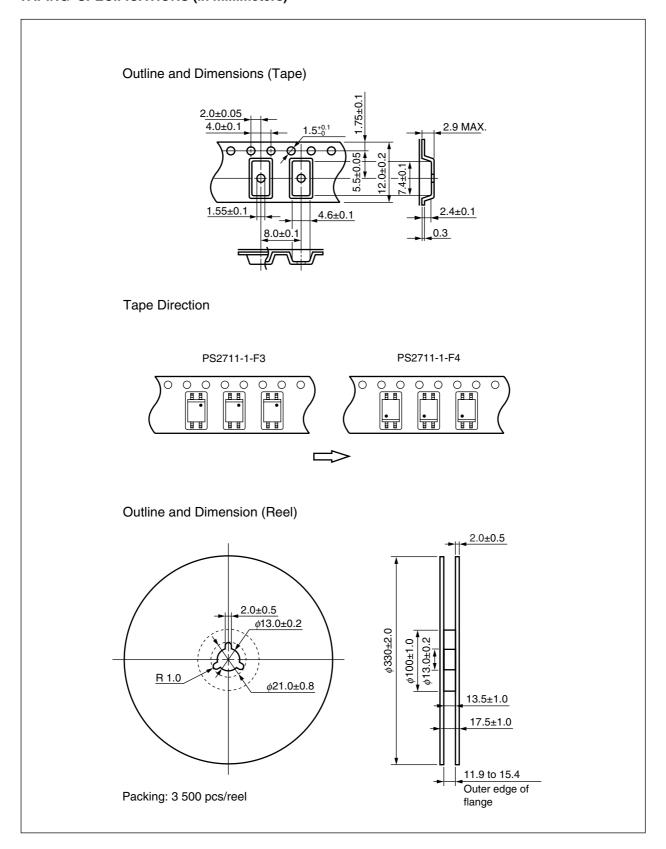


LONG TERM CTR DEGRADATION





TAPING SPECIFICATIONS (in millimeters)



NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

• Peak reflow temperature 260°C or below (package surface temperature)

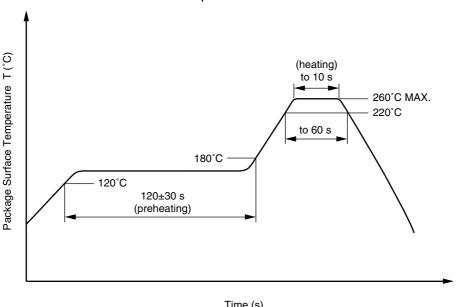
• Time of peak reflow temperature 10 seconds or less • Time of temperature higher than 220°C 60 seconds or less

• Time to preheat temperature from 120 to 180°C 120±30 s · Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

 Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

· Preheating conditions 120°C or below (package surface temperature)

· Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Soldering by soldering iron

• Peak temperature (lead part temperature) 350°C or below • Time (each pins) 3 seconds or less

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead.

(b) Please be sure that the temperature of the package would not be heated over 100°C.



(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

★ 3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.

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M8E 00.4-0110



Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

▶ For further information, please contact

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